

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Yi Ding

Assignee:

Mosel Vitelic, Inc.

Title:

Nonvolatile Memory Cells

With Buried Channel Transistors

Application No.:

10/632,155

Filing Date:

July 30, 2003

Examiner:

Unknown

Group Art Unit:

Unassigned

Docket No.:

M-15222 US

San Jose, California April 16, 2004

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97(b)

Dear Sir:

Pursuant to 37 CFR § 1.56, § 1.97 and § 1.98, the documents listed on the accompanying form PTO-1449 are called to the attention of the Examiner for the above patent application. Copies of these documents are enclosed.

Citation of these documents shall not be construed as:

- 1. an admission that the documents are necessarily prior art with respect to the instant invention;
 - 2. a representation that a search has been made, other than as described above; or
- 3. an admission that the information cited herein is, or is considered to be material to patentability as defined in § 1.56(b).

No fee is believed to be required. If a fee is required for this Information Disclosure Statement, please charge the fee to Deposit Account No. 50-2257. This paper is being submitted in duplicate.

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on April 16, 2004.

Attorney for Applicant

Date of Signature

Respectfully submitted,

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Attorney for Applicant(s)

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U.S. Department of Commerce, Patent and Trademark Office						Atty Docket No. Serial No.					
						M-15222 US			10/632,155		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT						Applicant					
(Use several sheets if necessary)						Yi Ding					
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U.S. Patent Documents											
*Examiner		Document						Т	Filing D		
Initial		Number	Date	Name		Class	Subcla	iss	If Approp	oriate	
-	AA	6,420,231	16 Jul. 2002	Harari et al.							
	AB	2003/0218908 A1	27 Nov. 2003	Park et al.							
	AC	2004/0004863 A1	8 Jan. 2004	Wang							
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	•	OTHER A	RT (Including Au	thor, Title, Date, Pe	rtinen	t Pages, E	tc.)	· ·	,		
AM United States Patent Application No. 10/798,475, entitled "Fabrication of Conductive Lines Interconnecting Conductive Gates in Nonvolatile Memories and Non-Volatile Memory Structures," Filed on March 10, 2004; Attorney Docket No. M-15296 US.											
	AN	United States Patent Application No. 10/797,972, entitled "Fabrication of Conductive Lines Interconnecting First Conductive Gates in Nonvolatile Memories Having Second Conductive Gates Provided By Conductive Gates Lines, Wherein The Adjacent Conductive Gate Lines For The Adjacent Columns Are Spaced From Each Other, And Non-Volatile Memory Structures," Filed on March 10, 2004; Attorney Docket No. M-15297 US.									
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Examiner	1		Date Considered			.		-			
	Initial i	f reference considere			mana	e with MF	PEP 609: F	Draw lii	ne through		
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.											